



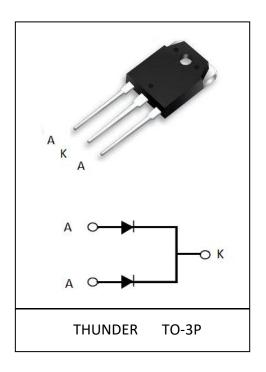
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 18A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	200 V	
lf(AV)	2*9A	
trr	18 ns	



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		200	V
Continuous forward current	lF(AV)	Tc =110°C	18	
Single pulse forward current	IFSM	Tc =25°C	180	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	45	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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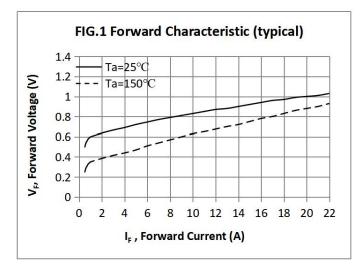
Electrical characteristics (Ta=25°C unless otherwise specified)

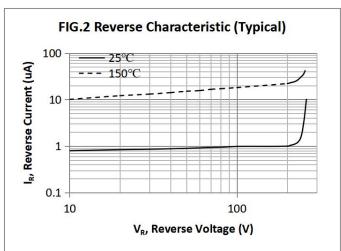
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	VBR,	IR=100⊬A	200			
Blocking voltage	V_R	III-100171	200			
Forward voltage (Per Diode)		IF=10 A		0.90	1.00	V
	VF	IF=10 A, Tj =125°C		0.77	0.90	
Reverse leakage current(Per Diode)		Vr= Vrrm			10	_
	Tj=150°C, Vr=200V			100	μ Α	
Reverse recovery time(Per Diode)	+	I _F =0.5A, I _R =1A, I _{RR} =0.25A		23	30	nc
	urr	I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		18	25	ns

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta$ JC	8.0	°C/W

Electrical performance (typical)

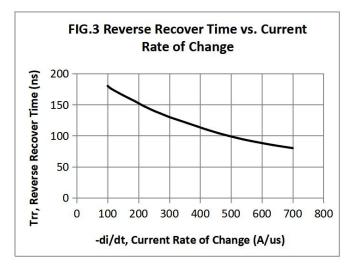


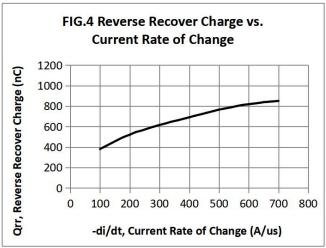


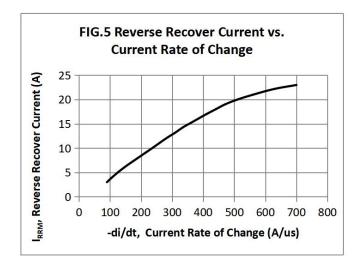
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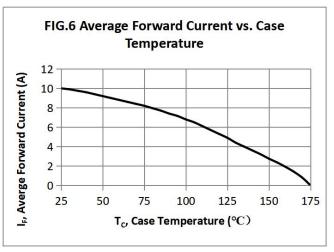


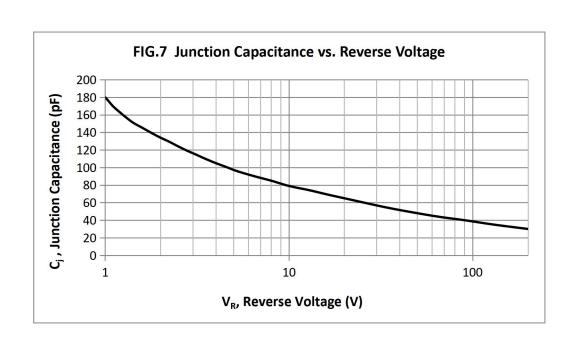












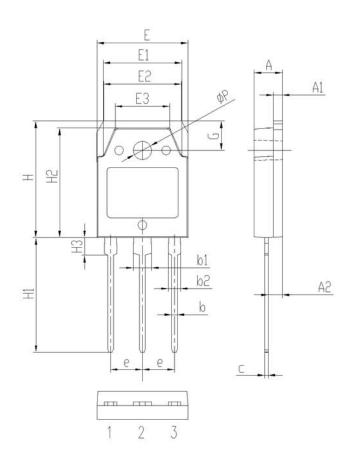
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Package Information

TO-3P PACKAGE



Symbol	Dimensions(millimeters)		
Symbol	Min.	Max.	
Α	4.60	5.00	
A1	1.30	1.70	
A2	2.20	2.60	
b	0.80	1.20	
b1	2.90	3.30	
b2	1.90	2.30	
С	0.40	0.80	
е	5.25	5.65	
E	15.3	15.7	
E1	13.2	13.6	
E2	13.1	13.5	
E3	9.10	9.50	
Н	19.7	20.1	
H1	19.1	20.1	
H2	18.3	18.7	
Н3	2.80	3.20	
G	4.80	5.20	
ΦР	3.00	3.40	

Notice

Thunder Microelectronics Incorporated Limited reserves the right to make changes without further notice to any products or specifications herein. When use the product, be sure to obtain the latest specification.

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-Headquarters

WuXi Thunder Microelectronics Incorporated Limited

Building E1-9F, No.200 LingHu Road, XinWu district, WuXi, China 214135

Tel:+86-510-85160109 Fax:+86-510-85160109

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